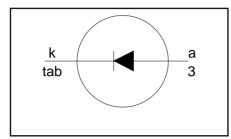
# BYW29EB, BYW29ED series

### **FEATURES**

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- Reverse surge capability
  High thermal cycling performance
  Low thermal resistance

### **SYMBOL**



### QUICK REFERENCE DATA

$$V_R = 150 \text{ V}/ 200 \text{ V}$$
 $V_F \le 0.895 \text{ V}$ 
 $I_{F(AV)} = 8 \text{ A}$ 
 $I_{RRM} = 0.2 \text{ A}$ 
 $t_{rr} \le 25 \text{ ns}$ 

### **GENERAL DESCRIPTION**

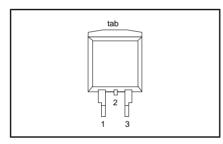
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYW29EB series is supplied in the SOT404 surface mounting package. The BYW29ED series is supplied in the SOT428 surface mounting package.

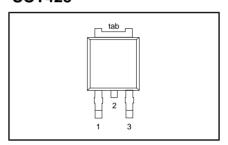
### **PINNING**

PIN	DESCRIPTION
1	no connection
2	cathode <sup>1</sup>
3	anode
tab	cathode

### **SOT404**



### **SOT428**



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	N. MAX.		UNIT
		BYW29EB/ BYW29ED		-150	-200	
$V_{RRM}$	Peak repetitive reverse		-	150	200	V
$V_{RWM}$	voltage Working peak reverse voltage		-	150	200	V
$V_R$	Continuous reverse voltage		-	150	200	V
I <sub>F(AV)</sub>	Average rectified forward current	square wave; $\delta = 0.5$ ; $T_{mb} \le 128$ °C	-	8	3	A
I <sub>FRM</sub>	Repetitive peak forward current	square wave; $\delta = 0.5$ ; $T_{mb} \le 128$ °C	-	1	6	A
I <sub>FSM</sub>	Non-repetitive peak forward current	t = 10  ms t = 8.3  ms sinusoidal; with reapplied $V_{RRM(max)}$	-	8 8	0 8	A A
I <sub>RRM</sub>	Peak repetitive reverse surge current	$t_p = 2 \mu s; \delta = 0.001$	-	0.	.2	A
I <sub>RSM</sub>	Peak non-repetitive reverse surge current	$t_p = 100 \ \mu s$	-	0	.2	A
T <sub>j</sub>	Operating junction temperature		-	15	50	°C
$T_{stg}$	Storage temperature		- 40	15	50	°C

<sup>1.</sup> It is not possible to make connection to pin 2 of the SOT428 or SOT404 packages.

BYW29EB, BYW29ED series

# **ESD LIMITING VALUE**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>C</sub>	l a	Human body model; C = 250 pF; R = 1.5 kΩ	-	8	kV

# THERMAL RESISTANCES

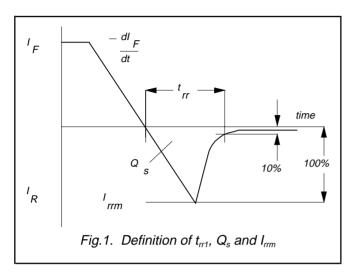
SYN	/BOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-r</sub>		Thermal resistance junction to mounting base		-	-	2.7	K/W
R <sub>th j-a</sub>	а		SOT404 and SOT428 packages, pcb mounted, minimum footprint, FR4 board	-	50	-	K/W

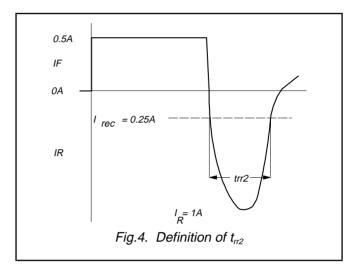
## **ELECTRICAL CHARACTERISTICS**

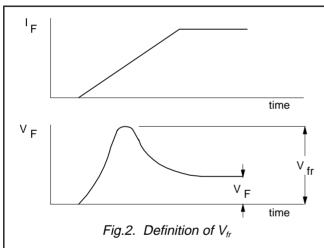
T<sub>i</sub> = 25 °C unless otherwise specified

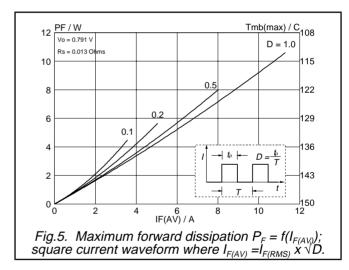
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{F}$	Forward voltage	$I_F = 8 \text{ A}; T_j = 150^{\circ}\text{C}$	-	0.8	0.895	V
		$I_{\rm F} = 8 \text{ A}$	-	0.92	1.05	V
		$I_{F} = 20 \text{ A}$	-	1.1	1.3	V
$ I_R $	Reverse current	$V_R = V_{RWM}$	-	2	10	μΑ
		$V_{R} = V_{RWM}^{m}; T_{i} = 100^{\circ}C$	-	0.2	0.6	mΑ
$Q_{rr}$	Reverse recovered charge	$V_R = V_{RWM}^{N,VWW}$ ; $T_j = 100^{\circ}C$ $I_F = 2 \text{ A}$ ; $V_R \ge 30 \text{ V}$ ; $-dI_F/dt = 20 \text{ A/}\mu\text{s}$	-	4	11	nC
	Reverse recovery time	$I_{\rm F} = 1 \text{ A}; V_{\rm R} \ge 30 \text{ V}; -dI_{\rm F}/dt = 100 \text{ A/}\mu\text{s}$		20	25	ns
4	Reverse recovery time	$I_F = 0.5 \text{ A to } I_R = 1 \text{ A}, I_{rec} = 0.25 \text{ A}$	-	15	20	ns
$V_{\rm fr}$	Forward recovery voltage	$l_F = 1 \text{ A}; dl_F/d\tilde{t} = 10 \text{ A/µs}$	-	1	-	V

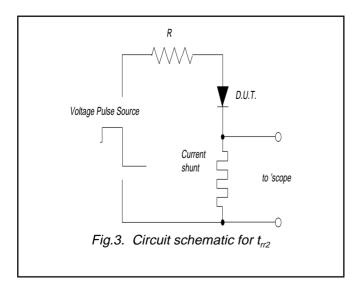
# BYW29EB, BYW29ED series











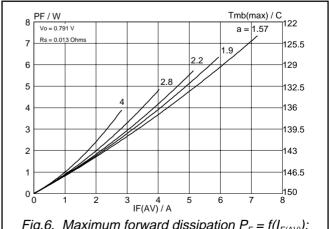
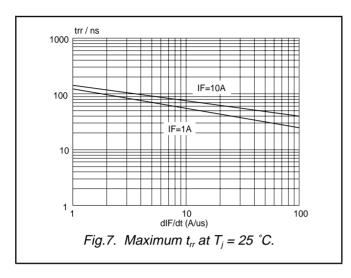
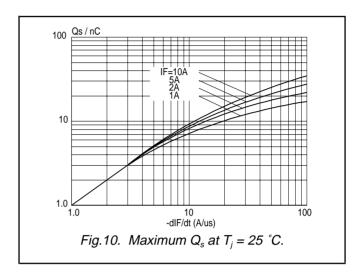
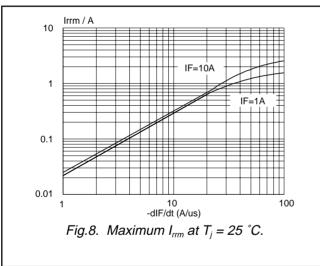


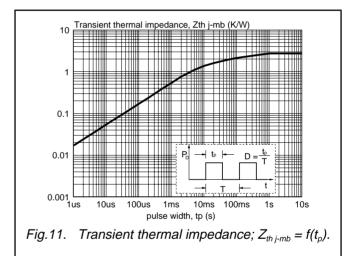
Fig.6. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; sinusoidal current waveform where a = form factor  $= I_{F(RMS)} / I_{F(AV)}$ .

# BYW29EB, BYW29ED series









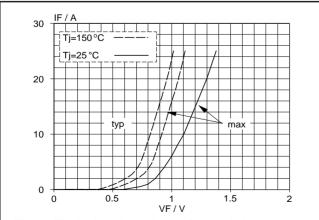
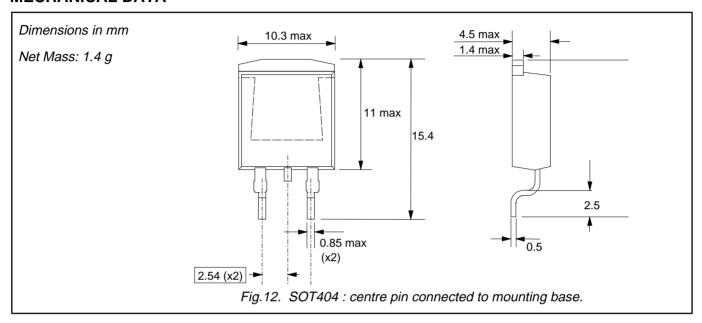


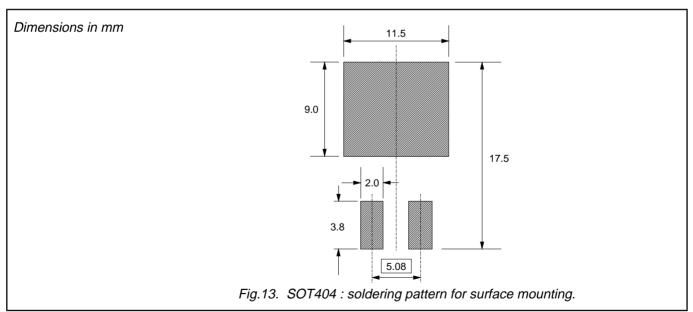
Fig.9. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 

# BYW29EB, BYW29ED series

## **MECHANICAL DATA**



# **MOUNTING INSTRUCTIONS**

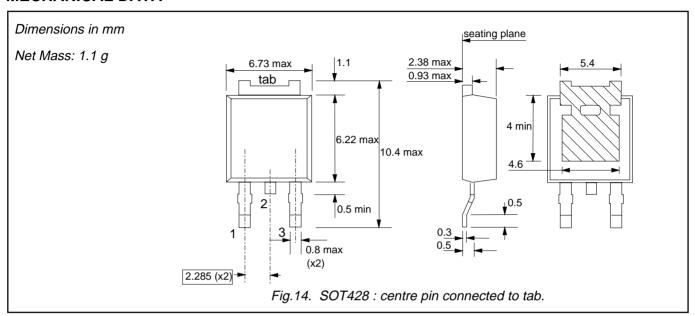


### **Notes**

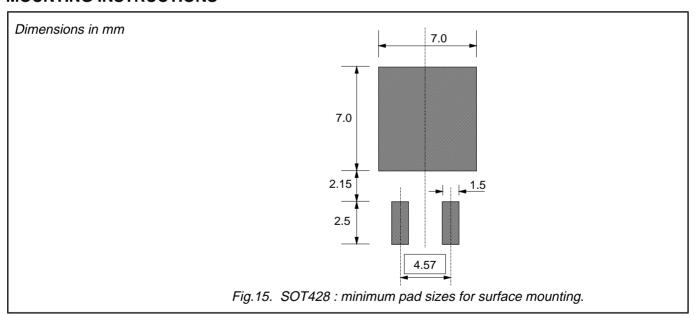
1. Epoxy meets UL94 V0 at 1/8".

# BYW29EB, BYW29ED series

### **MECHANICAL DATA**



## **MOUNTING INSTRUCTIONS**



### **Notes**

1. Plastic meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

# Rectifier diodes ultrafast, rugged

# BYW29EB, BYW29ED series

### **DEFINITIONS**

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of

this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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Philips Semiconductors Product specification

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